

isc Silicon PNP Power Transistor

2SB954

DESCRIPTION

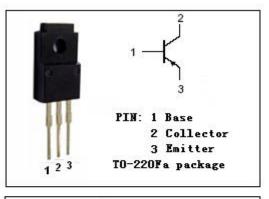
- Low Collector Saturation Voltage-
 - : V_{CE(sat)}= -1.0V(Max)@I_C= -1A
- Good Linearity of h_{FE}
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

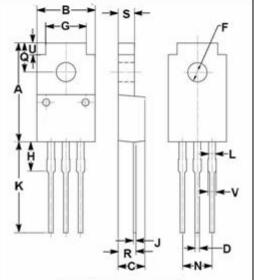
APPLICATIONS

• Designed for power amplifications.

ABSOLUTE MAXIMUM RATINGS(Ta=25 °C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{СВО}	Collector-Base Voltage	-60	V
V _{CEO}	Collector-Emitter Voltage	-60	V
V _{EBO}	Emitter-Base Voltage	-5	V
lc	Collector Current-Continuous	-1	А
I _{CM}	Collector Current-Peak	-2	А
Pc	Collector Power Dissipation @ T _a =25°C	2	W
	Collector Power Dissipation @ T _c =25°C	30	VV
TJ	Junction Temperature	150	°C
T _{stg}	Storage Temperature Range	-55~150	°C





	mm	
DIM	MIN	MAX
A	16.85	17.15
В	9.54	10.10
C	4.35	4.65
D	0.75	0.90
F	3.20	3.40
G	6.90	7.20
H	5.15	5.45
J	0.45	0.75
ĸ	13.35	13.65
L	1.10	1.30
N	4.98	5.18
Q	4.85	5.15
R	2.55	3.25
S	2.70	2.90
U	1.75	2.05
V	1.30	1.50

isc website: www.iscsemi.com

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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	Ic= -30mA; I _B = 0	-60			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = -1A; I _B = -0.125A			-1.0	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = -1A; V _{CE} = -4V			-1.3	V
I _{CEO}	Collector Cutoff Current	V _{CE} = -30V; I _B = 0			-300	μA
I _{CES}	Collector Cutoff Current	V _{CE} = -60V; V _{BE} = 0			-200	μA
Іево	Emitter Cutoff Current	V _{EB} = -5V; I _C = 0			-1	mA
h _{FE-1}	DC Current Gain	I _C = -0.2A; V _{CE} = -4V	70		250	
h _{FE-2}	DC Current Gain	I _C = -1A; V _{CE} = -4V	15			

h_{FE-1} Classifications

Q	Р		
70-150	120-250		

NOTICE:

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